# Low Voltage 1:2 Differential HSTL Clock Fanout Buffer

MC100ES8011H

The MC100ES8011H is a low voltage 1:2 Differential HSTL fanout buffer. Designed for the most demanding clock distribution systems, the MC100ES8011H supports various applications that require the distribution of precisely aligned differential clock signals. Using SiGe technology and a fully differential architecture, the device offers very low skew outputs and superior digital signal characteristics. Target applications for this clock driver are in high performance clock distribution in computing, networking and telecommunication systems.

### Features

- 1:2 differential clock fanout buffer
- 20 ps maximum device skew
- SiGe Technology
- Supports DC to 625 MHz operation
- HSTL compatible differential clock outputs
- HSTL compatible differential clock inputs
- 3.3V power supply
- Supports industrial temperature range
- Standard 8 lead SOIC package

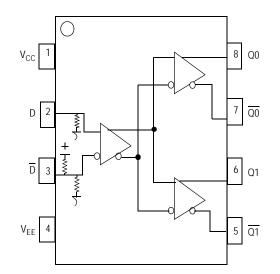
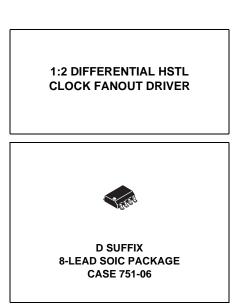


Figure 1. 8-Lead Pinout (Top View) and Logic Diagram



ORDERING INFORMATION
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Device	Package
MC100ES8011HD	SO-8
MC100ES8011HDR2	SO-8

PIN DESCRIPTION				
Pin	Pin Function			
D, D	HSTL Data Inputs			
Qn, Qn	HSTL Data Outputs			
V <sub>CC</sub>	Positive Supply			
V <sub>EE</sub>	Negative Supply			

IDT<sup>™</sup> Low Voltage 1:2 Differential HSTL Clock Fanout Buffer

### Table 1. Absolute Maximum Ratings<sup>(1)</sup>

Symbol	Parameter	Conditions	Rating	Unit	
V <sub>SUPPLY</sub>	Power Supply Voltage	Difference between V <sub>CC</sub> & V <sub>EE</sub>	3.9	V	
V <sub>IN</sub>	Input Voltage	$V_{CC} - V_{EE} \le 3.6V$	V <sub>CC</sub> + 0.3 V <sub>EE</sub> - 0.3	V V	
I <sub>OUT</sub>	Output Current	Continuous Surge	50 100	mA mA	
T <sub>A</sub>	Operating Temperature Range		-40 to +85	°C	
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C	

1. Absolute maximum continuous ratings are those maximum values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation at absolute-maximum-rated conditions is not implied.

Table 2. DC Characteristics (V<sub>CC</sub> =  $3.3 \text{ V} \pm 5\%$ ; T<sub>J</sub> = 0°C to  $110^{\circ}$ C)<sup>(1)</sup>

Symbol	Characteristic	Min	Тур	Max	Unit	Condition
HSTL differe	ential input signals (D, $\overline{D}$ )					•
$V_{DIF}$	Differential Input Voltage <sup>(2)</sup>	0.2			V	
$V_{X, IN}$	Differential Cross Point Voltage <sup>(3)</sup>	0.25	0.68 - 0.9	V <sub>CC</sub> – 1.3	V	
I <sub>IN</sub>	Input Current			±150	mA	$V_{IN} = V_X \pm 0.1V$
HSTL clock	outputs (Q[0:1], Q[0:1])				•	
$V_{X,  OUT}$	Output Differential Crosspoint	0.68	0.75	0.9	V	
V <sub>OH</sub>	Output High Voltage	1			V	
V <sub>OL</sub>	Ouput Low Voltage			0.4	V	
Supply Curr	ent					
I <sub>CC</sub>	Maximum Quiescent Supply Current without output termination current		80	105	mA	V <sub>CC</sub> pin (core)

1. DC characteristics are design targets and pending characterization.

2. V<sub>DIF</sub> (DC) is the minimum differential HSTL input voltage swing required for device functionality.

3.  $V_X(DC)$  is the crosspoint of the differential HSTL input signal. Functional operation is obtained when the crosspoint is within the V<sub>X</sub> (DC) range and the input swing lies within the V<sub>PP</sub> (DC) specification.

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Symbol	Characteristic	Min	Тур	Max	Unit	Condition
HSTL differ	ential input signals (D, $\overline{D}$ )				•	
$V_{DIF}$	Differential Input Voltage (peak-to-peak) <sup>(3)</sup>	0.4			V	
$V_{X, IN}$	Differential Cross Point Voltage <sup>(4)</sup>	0.68		0.9	V	
f <sub>CLK</sub>	Input Frequency			625	MHz	Differential
t <sub>PD</sub>	Propagation Delay D to Q[0:1}	700	920	1200	ps	Differential
HSTL clock	outputs (Q[0:1], Q[0:1])				•	
$V_{X,  OUT}$	Output Differential Crosspoint	0.68	0.75	0.9	V	
V <sub>OH</sub>	Output High Voltage	1			V	
V <sub>OL</sub>	Ouput Low Voltage			0.5	V	
V <sub>O(P-P)</sub>	Differential Output Voltage (peak-to-peak)	0.5			V	
t <sub>SK(O)</sub>	Output-to-Output Skew			20	ps	Differential
t <sub>SK(PP)</sub>	Output-to-Output Skew (part-to-part)			500	ps	Differential
t <sub>SK(P)</sub>	Output Pulse Skew			100	ps	
t <sub>JIT(CC)</sub>	Output Cycle-to-Cycle Jitter			1	ps	
t <sub>r</sub> / t <sub>f</sub>	Output Rise/Fall Times	150		800	ps	20% to 80%

### Table 3. AC Characteristics (V<sub>CC</sub> = $3.3 \text{ V} \pm 5\%$ ; T<sub>J</sub> = 0°C to $110^{\circ}$ C)<sup>(1)</sup> (2)

1. AC characteristics are design targets and pending characterization.

2. AC characteristics apply for parallel output termination of  $50\Omega$  to V<sub>TT.</sub> 3. V<sub>DIF</sub> (AC) is the minimum differential HSTL input voltage swing required to maintain AC characteristics including t<sub>PD</sub> and device-to-device skew.

4. V<sub>X</sub> (AC) is the crosspoint of the differential HSTL input signal. Functional operation is obtained when the crosspoint is within the V<sub>X</sub> (AC) range and the input swing lies within the V<sub>DIF</sub> (AC) specification. Violation of V<sub>X</sub> (AC) or V<sub>DIF</sub> (AC) impacts the device propagation delay, device and part-to-part skew.

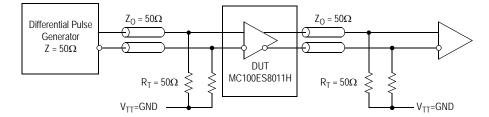


Figure 2. MC100ES8011H AC Test Reference

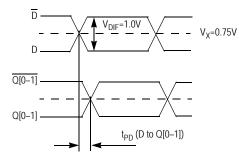
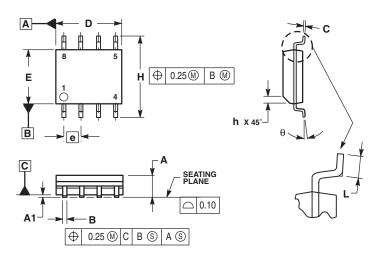


Figure 3. MC100ES8011H AC Reference Measurement Waveform (HSTL Input)

### PACKAGE DIMENSIONS



NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. DIMENSIONS ARE IN MILLIMETER. 3. DIMENSION AND E DO NOT INCLUDE MOLD PROTRUSION. 4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE. 5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS			
DIM	MIN	MAX		
Α	1.35	1.75		
A1	0.10	0.25		
В	0.35	0.49		
С	0.19	0.25		
D	4.80	5.00		
Е	3.80	4.00		
е	1.27	BSC		
Н	5.80	6.20		
h	0.25	0.50		
L	0.40	1.25		
θ	0°	7°		

**D SUFFIX 8-LEAD SOIC PACKAGE** CASE 751-06

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